# NSN 5961-00-828-1005

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# **Inclosure Material:**

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

0.450 inches

**Overall Width:** 

1.050 inches

# **Mounting Facility Quantity:**

2

# Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

Electrode Internally-electrically Connected To Case:

Collector

#### Mounting Method:

Unthreaded hole

# Features Provided:

Hermetically sealed case

# Semiconductor Material:

Germanium

# Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-base, emitter open and 25.0 breakdown voltage, collector-to-emitter, base open and 20.0 breakdown voltage, emitter-to-base, collector open and 30.0 collector to emitter voltage, dc with base short-circuited to emitter

# **Current Rating Per Characteristic:**

7.00 amperes source cutoff current and 2.00 amperes source cutoff current

# **Power Rating Per Characteristic:**

85.0 watts small-signal input power, common-collector absolute

# Maximum Operating Tempurature Per Measurement Point:

110.0 degrees celsius case

### **Special Features:**

Junction pattern arrangement: pnp

### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

#### **Specification Data:**

80131-release4882 professional/industrial association specification

# Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

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